

Supporting Information for

**Charge Engineering on Mo<sub>2</sub>C@defect-rich N-doped Carbon Nanosheets for Efficient Electrocatalytic H<sub>2</sub> Evolution**

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**S1 ECSA and TOF Calculation**

The electrochemical active surface area (ECSA) can be estimated using the capacitance (C). The specific capacitance for a flat surface is generally found to be in the range of 20~60 μF cm<sup>-2</sup>. In the following calculations of the ECSA and turnover frequency (TOF), 40 μF cm<sup>-2</sup> was used as literatures.

Generally, we calculated the ECSA of each sample according to the capacitance measurement (Eq. (S1)):

$$\text{ECSA} = \frac{C}{40 \mu\text{F cm}^{-2} \text{ per cm}^{-2}} \quad (\text{S1})$$

Where, C represents the capacitance;  $40 \mu\text{F cm}^{-2}$  was used in the above formula. To further comprehend the inherent electrocatalytic performance of each sample, the turnover frequency (TOF) was also estimated by Eq. (S2):

$$\text{TOF} = \frac{\text{number of total hydrogen turnover per cm}^{-2}}{\text{number of active sites per cm}^{-2}} = \frac{\#_{\text{H}_2} \times |j|}{\text{active sites} \times \text{ECSA}} \quad (\text{S2})$$

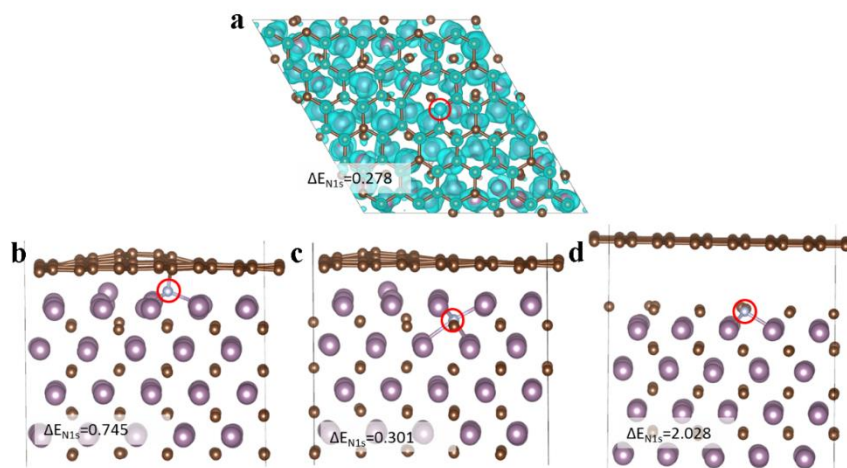
The number of total hydrogen turnovers ( $\#_{\text{H}_2}$ ) was calculated from the current density according to Eq. (S3):

$$\begin{aligned} \#_{\text{H}_2} &= \left( j \frac{\text{mA}}{\text{cm}^2} \right) \left( \frac{1 \text{C s}^{-1}}{1000 \text{ mA}} \right) \left( \frac{1 \text{mol H}_2}{96485.3 \text{ C}} \right) \left( \frac{1 \text{mol H}_2}{2 \text{mol of e}^-} \right) \left( \frac{6.02 \times 10^{23} \text{H}_2 \text{ moleculars}}{1 \text{ mol H}_2} \right) \\ &= 3.12 \times 10^{15} \frac{\text{H}_2/\text{s}}{\text{cm}^2} \text{ per } \frac{\text{mA}}{\text{cm}^2} \quad (\text{S3}) \end{aligned}$$

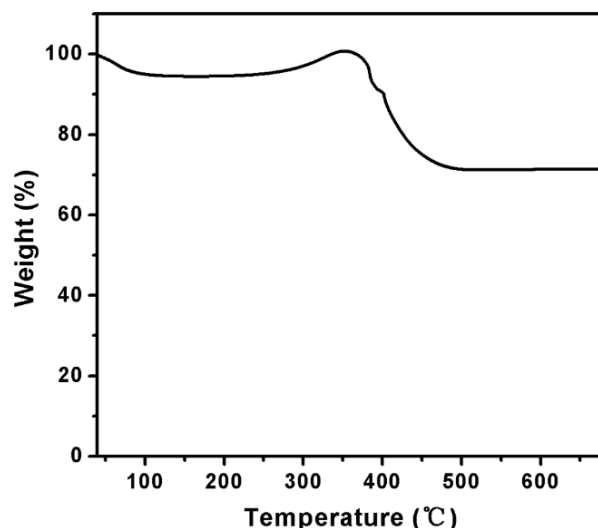
The number of active sites per surface area was calculated according to the crystal data as Eq. (S4):

$$\text{Active sites}_{\text{Mo}_2\text{C}} = \left( \frac{2 \text{ atom/unit cell}}{37.2 \text{ \AA}^3/\text{unit cell}} \right)^{\frac{2}{3}} = 1.42 \times 10^{15} \text{ atom per cm}^2 \quad (\text{S4})$$

## S2 Supplementary Figures and Tables



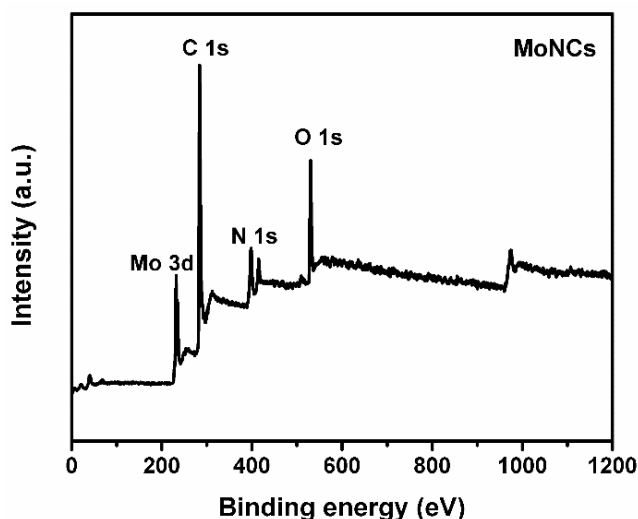
**Fig. S1** The charge distribution of **a** C-terminated  $\text{Mo}_2\text{C}@N$  doped graphene with pyridinic-N dopant. Illustration of  $\text{Mo}_2\text{C}@N$  doped graphene with N **b** on surface and **c** in bulk Mo-terminated  $\text{Mo}_2\text{C}$  and **d** in top surface C layer of C-terminated  $\text{Mo}_2\text{C}$ . Red circled is N atom. The figures are plotted with VESTA



**Fig. S2** TGA curve of MoNCs under air flow

As depicted in TGA curve, the initial weight losses below 100 °C is due to the water evaporation, followed by a gradual oxidation and transformation from  $\text{Mo}_2\text{C}$  to  $\text{MoO}_3$ . When heating to above 350 °C, the sample appeared markedly weight loss as a result of the combustion of carbon. As the temperature continuously after raised to 500 °C, the weight loss nearly showed no fluctuation, indicating the only remaining product was  $\text{MoO}_3$  (about 70 wt% from the TGA curve). The  $\text{Mo}_2\text{C}$  content in MoNCs was calculated by Eq. (S5):

$$\begin{aligned} m(\text{Mo}_2\text{C}) &= m(\text{residual mass}) \times M(\text{Mo}_2\text{C}) / (2 \times M(\text{MoO}_3)) \\ &= 70\% \times 204 / (2 \times 144) \\ &= 49.58\% \end{aligned}$$



**Fig. S3** The survey spectrum of MoNCs

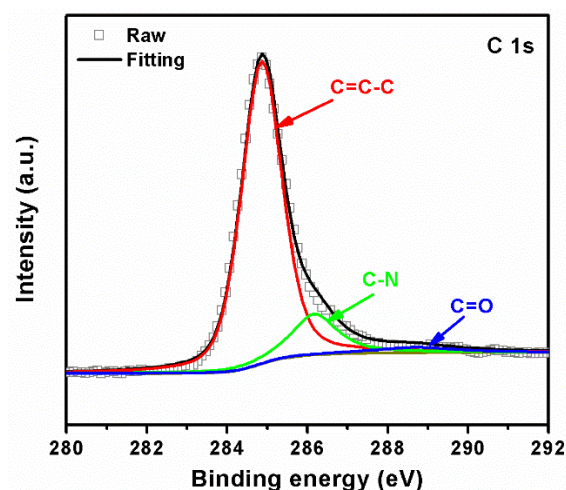


Fig. S4 C 1s XPS spectrum of MoNCs

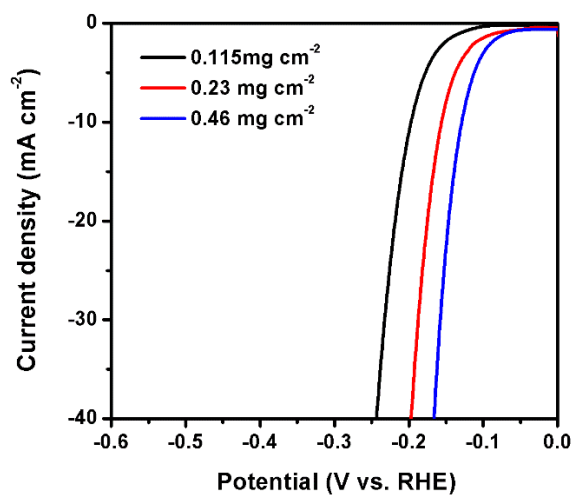


Fig. S5 LSV curves of MoNCs electrocatalyst with different loading amounts

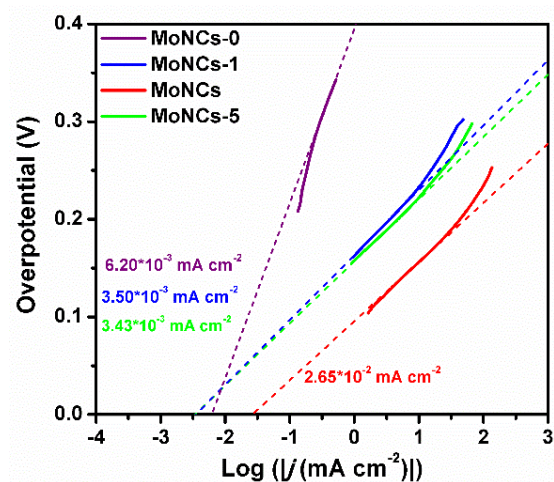
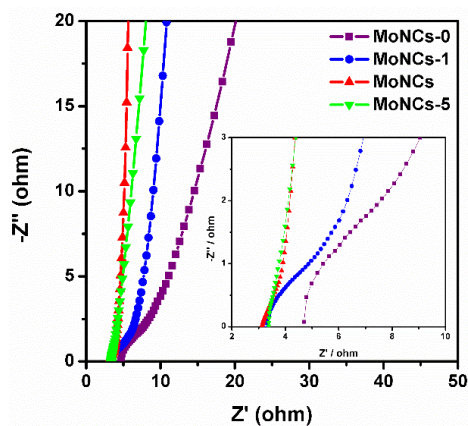
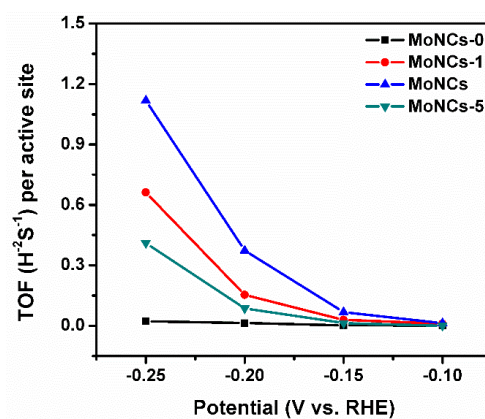


Fig. S6 The calculated exchange current density by Tafel plot



**Fig. S7** Nyquist plots of electrochemical impedance spectroscopy for different samples



**Fig. S8** TOF values of different samples

**Table S1** The atom percentage of different elements in MoNC<sub>s-x</sub> by XPS measurement

Samples	Mo	C	N	O
MoNCs-0	4.45	79.17	0	16.38
MoNCs-1	4.02	78.26	1.34	16.34
MoNCs	3.4	81.82	1.46	13.34
MoNCs-5	0.9	91.5	1.88	5.72

**Table S2** Electrochemical parameters of different comparison samples

Samples	Onset potential (mV)	$\eta_{10}$ (mV)
MoNCs-0	391	-
MoNCs-1	163	233
MoNCs	83	157
MoNCs-5	158	223

**Table S3** The comparison of HER performances in 0.5 M H<sub>2</sub>SO<sub>4</sub> and synthesis method with other Mo-based catalysts

Catalysts	Onset potential (mV)	$\eta_{10}$ (mV)	Tafel slope (mV dec <sup>-1</sup> )	$j_0$ (mA cm <sup>-2</sup> )	Synthesis method	Refs.
MoNCs	83	157	60.6	$2.65 \times 10^{-2}$	a one-step pyrolysis	<b>This work</b>
MoP	~120	240	66	-	annealed MoS <sub>2</sub> and red phosphorus in Ar/H <sub>2</sub>	<i>Adv. Mater.</i> , <b>2016</b> , 28, 1427-1432
MoSe <sub>2</sub> /Mo core-shell nanoscrews	89	166	34.7	-	two-stage sputtering processes for preparing Mo film, then low-temperature plasma-assisted selenization process for producing sample	<i>Adv. Mater.</i> , <b>2016</b> , 28, 9831-9838
Monolayer MoS <sub>2</sub> /3D gold	118	226	46	-	chemically dealloying prepare NPG, then prepare MoS <sub>2</sub> by CVD method	<i>Adv. Mater.</i> , <b>2014</b> , 26, 8023-8028
Co <sub>0.6</sub> Mo <sub>1.4</sub> N <sub>2</sub>	-	200	-	0.23	multiple step	<i>J. Am. Chem. Soc.</i> , <b>2013</b> , 135, 19186-19192
Double-gyroid MoS <sub>2</sub>	150-200	240	50	$1.3-6.9 \times 10^{-4}$	TMDC based on Mo, Se, and Te with different composition were grown by MBE on HOPG under UHV conditions	<i>Nat. Mater.</i> , <b>2012</b> , 11, 963-969
Mo <sub>2</sub> C nanotubes	-	172	62	$1.7 \times 10^{-2}$	by carburizing Mo-polydopamine nanotubes under a N <sub>2</sub> gas flow	<i>Angew. Chem. Int. Ed.</i> , <b>2015</b> , 54, 15395-15399
MoSe <sub>2</sub> /carbon fiber paper	110	250	59.8	$3.8 \times 10^{-4}$	electrodeposition of Mo into a silica template followed by sulphidization with H <sub>2</sub> S	<i>Nano Lett.</i> , <b>2013</b> , 13, 3426-3433
MoSe <sub>0.12</sub> Te <sub>1.79</sub>	180	410	62	-	via a solid-state reaction under Ar using (NH <sub>4</sub> ) <sub>6</sub> Mo <sub>7</sub> O <sub>24</sub> ·4H <sub>2</sub> O and ALG	<i>Adv. Energy Mater.</i> , <b>2018</b> , 1800031
Mo <sub>2</sub> C/GCSs	120	200	62.6	$1.25 \times 10^{-2}$	Mo <sub>2</sub> CT <sub>x</sub> and Ti <sub>2</sub> CT <sub>x</sub> MXenes were synthesized by HF etching of their parent ternary carbides, Mo <sub>2</sub> Ga <sub>2</sub> C and Ti <sub>2</sub> AlC, by removing the Ga and Al atoms, respectively	<i>ACS Catal.</i> , <b>2014</b> , 4, 2658-2661
Mo <sub>2</sub> CT <sub>x</sub> MXenes	~100	283	70	-	chemical vapor deposition, including by using a microwave-assisted intercalation method.	<i>ACS Energy Lett.</i> , <b>2016</b> , 1, 589-594
NiMoN <sub>x</sub> /C (nitrides)	157	225	35.9	-	Mo reacted with sulfur or selenium vapor	<i>Energy Environ. Sci.</i> , <b>2014</b> , 7, 2608-2613